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# 2MBI1400VXB-120P-54

Fuji Electric

GBT MODULE (V series) 1200V / 1400A / 2 in one package

Any questions, please feel free to contact us. info@kaimte.com



# 2MBI1400VXB-120P-50

**IGBT Modules** 

# **IGBT MODULE (V series)** 1200V / 1400A / 2 in one package

## Features

High speed switching Voltage drive Low Inductance module structure

### Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines

# Maximum Ratings and Characteristics

Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions		Maximum ratings	Units
Collector-Emitter voltage	VCES			1200	V
Gate-Emitter voltage	Vges			±20	V
L	lc	Continuous	Tc=25°C	1800	
		Continuous	Tc=100°C	1400	
Collector current	Ic pulse	1ms		2800	А
드 -	-lc			1400	
	-lc pulse	1ms		2800	
Collector power dissipation	Pc	1 device		7650	W
unction temperature	Tj			175	
perating junction temperature (under switching conditions)	Tjop			150	°C
Case temperature	Tc			150	C
Storage temperature	Tstg			-40 ~ +150	
between terminal and copper base (*1)	-V <sub>iso</sub>	AC : 1min.		4000	VAC
solation voltage between terminal and copper base (1) between thermistor and others (*2)	Viso	AC . IIIIII.		4000	VAC
Mounting		M5		6.0	
Screw torque (*3) Main Terminals	]-	M8	M8 M4		Nm
Sense Terminals	]	M4			

Note \*1: All terminals should be connected together during the test.

Note \*2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test. Note \*3: Recommendable Value : Mounting 3.0 ~ 6.0 Nm (M5) Recommendable Value : Main Terminals 8.0 ~ 10.0 Nm (M8) Recommendable Value : Sense Terminals 1.8 ~ 2.1 Nm (M4)

# • Electrical characteristics (at Ti= 25°C unless otherwise specified)

ama	Symbolo	Conditions	O and difficure		Characteristics		Unite
ems	Symbols	Conditions		min.	typ.	max.	Units
Zero gate voltage collector current	ICES	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V		-	-	12.0	mA
Gate-Emitter leakage current	IGES	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	2400	nA
Gate-Emitter threshold voltage	V <sub>GE (th)</sub>	Vce = 20V, Ic = 1400mA		6.0	6.5	7.0	V
	VCE (sat)		Tj=25°C	-	1.75	2.20	V
	(terminal)		Tj=125°C	-	2.10	-	
Collector Emitter saturation voltage	(*4)	V <sub>GE</sub> = 15V	Tj=150°C	-	2.15	-	
Collector-Emitter saturation voltage	V	Ic = 1400A	Tj=25°C	-	1.65	2.10	
	V <sub>CE (sat)</sub>		Tj=125°C	-	2.00	-	
	(chip)		Tj=150°C	-	2.05	-	
Input capacitance	Cies	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz		-	128	-	nF
Turn-on time	ton			-	1.00	-	μs
	tr			-	0.40	-	
	tr (i)			-	0.15	-	
	toff	$-R_{\rm G} = 1.6\Omega$			1.20	-	
Turn-off time	tf	-1.022	-	0.15	-		
	VF		Tj=25°C	-	1.90	2.35	_
	(terminal)		Tj=125°C	-	2.05	-	
Forward on voltage	(*4)	$V_{GE} = 0V$	Tj=150°C	-	2.00	-	v
	VF	I⊧ = 1400A	Tj=25°C	-	1.80	2.25	v
			Tj=125°C	-	1.95	-	
	(chip)		Tj=150°C	-	1.90	-	1
Reverse recovery time	trr	I <sub>F</sub> = 1400A		-	0.20	-	μs
Pasistanas	R	T=25°C T=100°C		-	5000	-	Ω
Resistance B value	R			465	495	520	12
B value	В	T=25/50°C		3305	3375	3450	K

Note \*4: Please refer to page 6 , there is definition of on-state voltage at terminal.

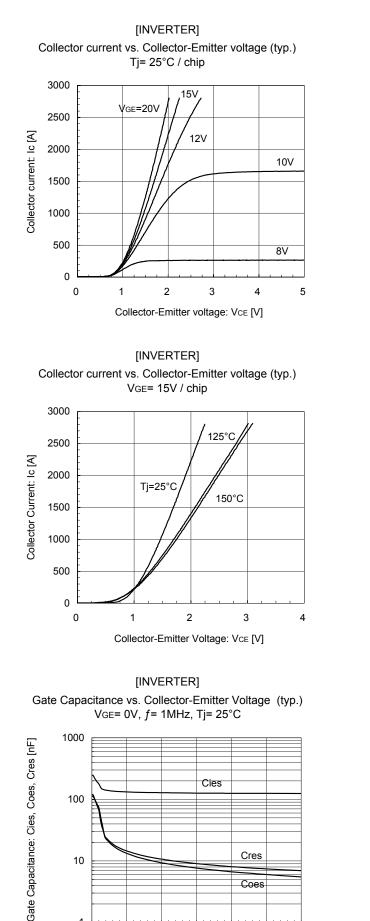
#### Thermal resistance characteristics

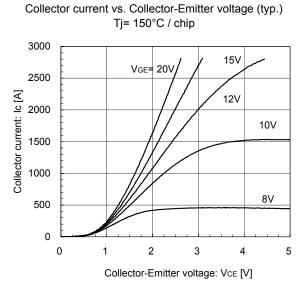
Itomo	Symbols	Conditions	Characteristics			Units
Items			min.	typ.	max.	Units
Thermal resistance (1device)	Rth(j-c)	Inverter IGBT	-	-	0.0195	°C/W
		Inverter FWD	-	-	0.0360	
Contact thermal resistance (1device) (*5)	Rth(c-f)	with Thermal Compound	-	0.00420	-	

Note \*5: This is the value which is defined mounting on the additional cooling fin with thermal compound.



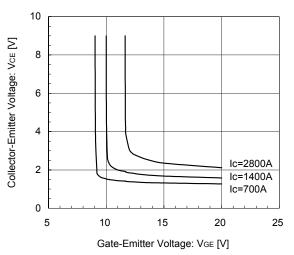
# Characteristics (Representative)



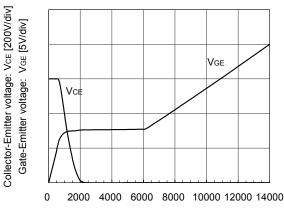


[INVERTER]

[INVERTER] Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj= 25°C / chip



[INVERTER] Dynamic Gate Charge (typ.) Vcc=600V, Ic=1400A, Tj= 25°C



Gate charge: Qg [nC]

Cres

Coes

25

30

20

15

Collector-Emitter voltage: VCE [V]

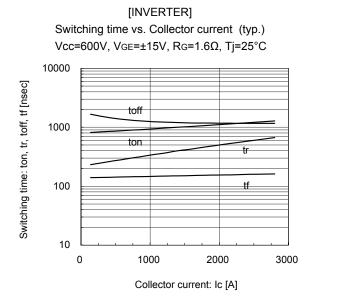
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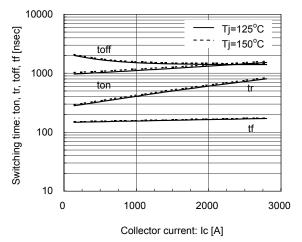
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5

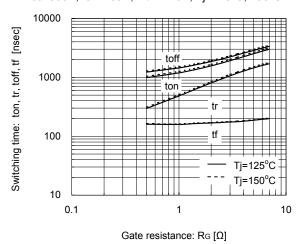
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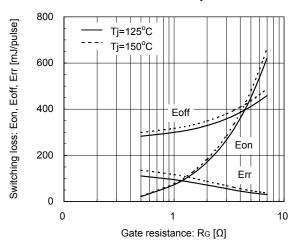
[INVERTER] Switching time vs. Collector current (typ.) Vcc=600V, Vge=±15V, Rg=1.6Ω, Tj=125°C, 150°C



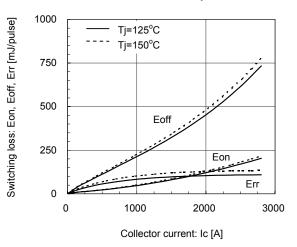
[INVERTER] Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=1400A, VgE=±15V, Tj=125°C, 150°C



[INVERTER] Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=1400A, Vge=±15V, Tj=125°C, 150°C

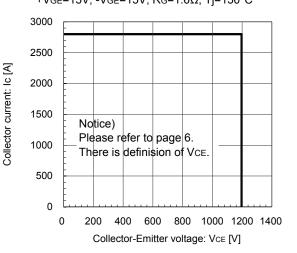


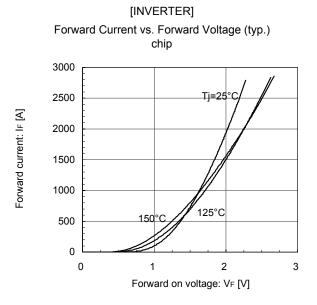
 $[INVERTER] \\ Switching loss vs. Collector current (typ.) \\ Vcc=600V, V_{GE}=\pm15V, R_{G}=1.6\Omega, T_{J}=125^{\circ}C, 150^{\circ}C$ 



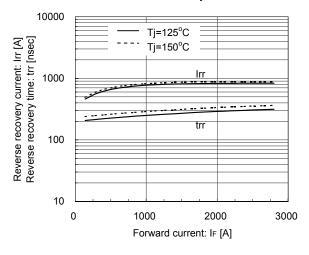
### [INVERTER]

Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, RG=1.6Ω, Tj=150°C



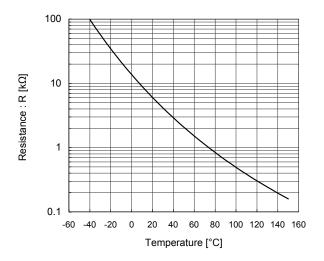


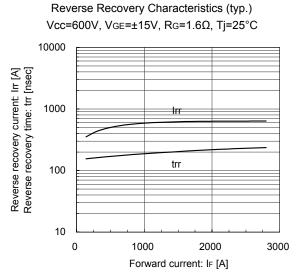
[INVERTER] Reverse Recovery Characteristics (typ.) Vcc=600V, Vge=±15V, Rg=1.6Ω, Tj=125°C, 150°C



# [THERMISTOR]

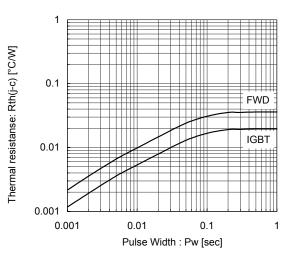
Temperature characteristic (typ.)



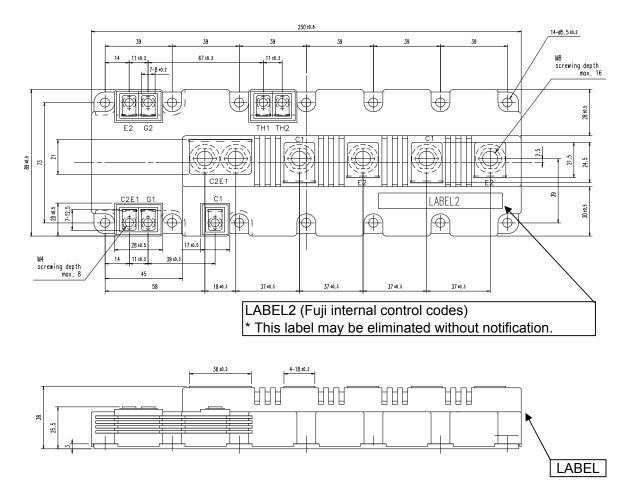


[INVERTER]

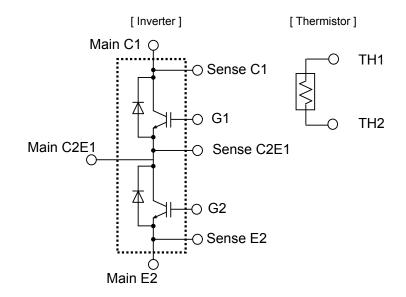
Transient Thermal Resistance (max.)



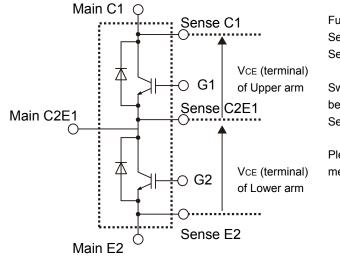
# Outline Drawings, mm



Equivalent Circuit Schematic



# Definition of on-state voltage at terminal and switching characteristics



Fuji defined VcE value of terminal by using Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm .

Switching characteristics of VCE also is defined between Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm .

Please use these terminals whenever measure spike voltage and on-state voltage .

# WARNING

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it is imperative to co	ontact Fuji Electric Co., Ltd.	equipment requiring higher reliants obtain prior approval. When the equipment from malfunction	using these products for su	ch equipment, take adequate
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6. Do not use product (without limitation).	s in this Catalog for the equ	ipment requiring strict reliability	such as the following and e	equivalents to strategic equipment
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